9. The method for recovering copper indium gallium selenide material according to claim 1, further comprising in step G that gallium hydroxide is placed in a drying oven and dried at a constant temperature of 80 °C for more than 8 hours, followed by heating in a muffle furnace to 700 °C and keeping at a constant temperature for 2 hours to give gallium oxide.

10. The method for recovering copper indium gallium selenide material according to claim 1, further comprising in step H that the indium hydroxide precipitate is reversely dissolved by 600 ml of 10% hydrochloric acid, followed by adjusting the pH to 1.5, heating to 55 °C and stirring at a constant temperature and at a stirring rate of 200 r/min.